

# Temenuga Hristova-Vasileva

## List of Publications by Year in descending order

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26  
papers

81  
citations

1684188  
5  
h-index

1474206  
9  
g-index

26  
all docs

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docs citations

26  
times ranked

93  
citing authors

#	ARTICLE	IF	CITATIONS
1	Electronic structure and plasmonic activity in co-evaporated Ag-In bimetallic alloys. <i>Journal of Alloys and Compounds</i> , 2022, 897, 163253.	5.5	5
2	Thin Ag/Bi coatings as epsilon-near-zero material with low optical losses. <i>Optical Materials</i> , 2022, 124, 112040.	3.6	3
3	Influence of fast neutron irradiation on the phase composition and optical properties of homogeneous Si <sub>x</sub> O <sub>x</sub> and composite Si <sub>x</sub> –Si <sub>x</sub> O <sub>x</sub> thin films. <i>Journal of Materials Science</i> , 2021, 56, 3197-3209.	3.7	2
4	Properties of ZnSe nanocrystalline thin films prepared by thermal evaporation. <i>Journal of Physics: Conference Series</i> , 2021, 1762, 012036.	0.4	0
5	Spectroscopic ellipsometry investigation of electronic states and optical properties of thin films from Ge <sub>30</sub> As <sub>x</sub> Se <sub>70-x</sub> system. <i>Journal of Non-Crystalline Solids</i> , 2020, 538, 120048.	3.1	0
6	In-depth evolution of tellurium films deposited by Frequency Assisted Thermal Evaporation in Vacuum (FATEV). <i>Journal of Physics: Conference Series</i> , 2019, 1186, 012026.	0.4	1
7	Changes in composite nc-Si-SiO <sub>2</sub> thin films caused by 20 eV MeV electron irradiation. <i>Nuclear Instruments &amp; Methods in Physics Research B</i> , 2019, 458, 159-163.	1.4	2
8	Room temperature sensitivity of ZnSe nanolayers to ethanol vapours. <i>Journal of Physics: Conference Series</i> , 2019, 1186, 012023.	0.4	2
9	Surface modification and chemical sensitivity of sol gel deposited nanocrystalline ZnO films. <i>Materials Chemistry and Physics</i> , 2018, 209, 165-171.	4.0	18
10	Influence of 20 eV MeV electron irradiation on the optical properties and phase composition of Si <sub>x</sub> O <sub>x</sub> thin films. <i>Journal of Applied Physics</i> , 2018, 123, 195303.	2.5	12
11	As <sub>2</sub> Se <sub>3</sub> thin films deposited by frequency assisted thermal evaporation – morphology and structure. <i>Journal of Physics: Conference Series</i> , 2017, 794, 012015.	0.4	2
12	Phase Equilibria in the Sb <sub>2</sub> Te <sub>3</sub> –InSb System. <i>Journal of Phase Equilibria and Diffusion</i> , 2016, 37, 524-531.	1.4	0
13	Influence of the thickness on the morphology and sensing ability of thermally-deposited tellurium films. <i>Journal of Physics: Conference Series</i> , 2016, 700, 012037.	0.4	0
14	“Cymatics” of selenium and tellurium films deposited in vacuum on vibrating substrates. <i>Surface and Coatings Technology</i> , 2016, 307, 542-546.	4.8	6
15	Phase Equilibria in the TeO <sub>2</sub> -CdI <sub>2</sub> System. <i>Journal of Phase Equilibria and Diffusion</i> , 2014, 35, 575-580.	1.4	0
16	Region of glass formation and main physicochemical properties of glasses from the As <sub>2</sub> Se <sub>3</sub> –Ag <sub>4</sub> S <sub>2</sub> –PbTe system. <i>Journal of Alloys and Compounds</i> , 2013, 573, 32-36.	5.5	2
17	Thermodynamic Investigations of Chalcogenide Glasses from the GeSe <sub>2</sub> –Sb <sub>2</sub> Te <sub>3</sub> –CdTe System. <i>Solid State Phenomena</i> , 2012, 194, 179-182.	0.3	0
18	Cooling rate and situation of the glass-forming border in the GeSe <sub>2</sub> -Sb <sub>2</sub> Te <sub>3</sub> -PbSb <sub>2</sub> Te <sub>4</sub> system. <i>Revue De Metallurgie</i> , 2012, 109, 21-26.	0.3	0

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19	New chalcogenide glasses in the GeSe <sub>2</sub> -Sb <sub>2</sub> Te <sub>3</sub> -CdTe system. <i>Revue De Metallurgie</i> , 2012, 109, 17-20.	0.3	2
20	Phase Equilibria in the GeSe <sub>2</sub> -Ag <sub>4</sub> SSe system. <i>Journal of Phase Equilibria and Diffusion</i> , 2012, 33, 106-109.	1.4	1
21	Phase equilibria in the Ag <sub>4</sub> SSe-PbTe system. <i>Thermochimica Acta</i> , 2012, 531, 42-45.	2.7	4
22	Glass-formation and phase transformation parameters of chalcogenide glasses from the GeSe <sub>2</sub> -GeTe-ZnTe system. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2011, 8, 3139-3142.	0.8	1
23	Microstructural, MOrphological And Optical Characterization of As <sub>2</sub> Se <sub>3</sub> -As <sub>2</sub> Te <sub>3</sub> -Sb <sub>2</sub> Te <sub>3</sub> Amorphous Layers. <i>NATO Science for Peace and Security Series B: Physics and Biophysics</i> , 2009, , 357-360.	0.3	0
24	Glass formation in the As <sub>2</sub> Se <sub>3</sub> -As <sub>2</sub> Te <sub>3</sub> -Sb <sub>2</sub> Te <sub>3</sub> system. <i>Journal of Physics and Chemistry of Solids</i> , 2008, 69, 2540-2543.	4.0	5
25	Glass formation in the As-Te-Sb system. <i>Materials Chemistry and Physics</i> , 2007, 105, 53-57.	4.0	10
26	Glass formation in the As <sub>2</sub> Te <sub>3</sub> -As <sub>2</sub> Se <sub>3</sub> -SnTe system. <i>Materials Letters</i> , 2007, 61, 3676-3678.	2.6	3